

#### **465V NPN HIGH VOLTAGE POWER TRANSISTOR**

#### **Features**

- BV<sub>CEO</sub> > 465V
- BV<sub>CES</sub> > 800V
- BV<sub>EBO</sub> > 9V
- I<sub>C</sub> = 1.5A high Continuous Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

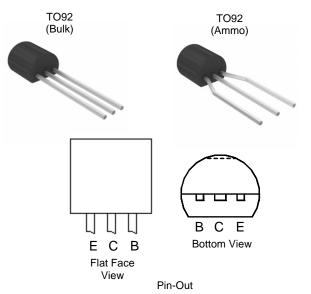
### **Applications**

Low power AC-DC SMPS for:

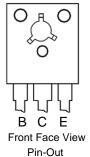
- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED lighting

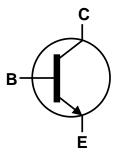
# Mechanical Data

- Case: TO92 or TO126
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 <sup>3</sup>
- Weight: TO92: 200mg (Approximate)
  TO126: 400mg (Approximate)









Device Schematic

### Ordering Information (Note 4)

| Product         | Package              | Marking    | Quantity                   |  |
|-----------------|----------------------|------------|----------------------------|--|
| APT13003HZ-G1   | TO92 (Straight Legs) | 13003HZ-G1 | 10,000 Bulk, Loose per Box |  |
| APT13003HZTR-G1 | TO92 (Joggled Legs)  | 13003HZ-G1 | 2,000 Taped, per Ammo Box  |  |
| APT13003HU-G1   | TO126                | GU13003H   | 4,000 Bulk, Loose per Box  |  |

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**





Manufacturers' code marking
 For TO92: 13003HZ-G1= Product Type Marking ID
 For TO126: GU13003H = Product Type Marking ID
 YWW = Date Code Marking
 e.g. 312 = Year 2013, Week 12.

8 = Assembly site code XX = Batch Number



# Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic                                   | Symbol           | Value | Unit |
|--|------------------|-------|------|
| Collector-Emitter Voltage (V <sub>BE</sub> = 0V) | V <sub>CES</sub> | 800   | V    |
| Collector-Emitter Voltage                        | V <sub>CEO</sub> | 465   | V    |
| Emitter-Base Voltage                             | V <sub>EBO</sub> | 9     | V    |
| Continuous Collector Current                     | Ic               | 1.5   | Α    |
| Peak Pulse Collector Current(Note 5)             | Ісм              | 3     | A    |
| Continuous Base Current                          | I <sub>B</sub>   | 0.75  | A    |
| Peak Pulse Base Current (Note 5)                 | Івм              | 1.5   | Α    |

Note:

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

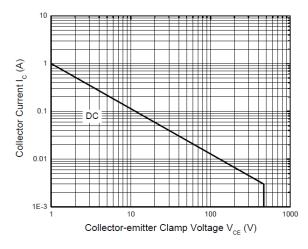
| Characteristic                              |                                    | Symbol              | Value       | Unit |  |
|---|------------------------------------|---------------------|-------------|------|--|
| Dower Discipation                           | For TO92                           | 0                   | 1.1         | 10/  |  |
| Power Dissipation                           | For TO126 @ T <sub>C</sub> = +25°C |                     | 20          | W    |  |
| Thormal Basistanas, Jungtian to Ambient Air | For TO92                           | D                   | 113.6       | °C/W |  |
| Thermal Resistance, Junction to Ambient Air | For TO126                          | $R_{	heta JA}$      | 96          | C/VV |  |
| Thermal Resistance, Junction to Case        | For TO92                           | D                   | 83.3        | °C/W |  |
| mermai Resistance, Junction to Case         | For TO126                          | $R_{	heta JC}$      | 6.25        |      |  |
| Operating and Storage Temperature Range     |                                    | $T_{J}$ , $T_{STG}$ | -65 to +150 | °C   |  |

### ESD Ratings (Note 6)

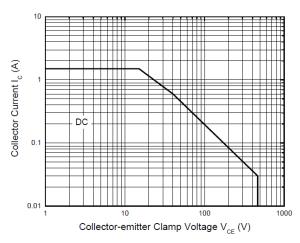
| Characteristic                             | Symbol  | Value   | Unit | JEDEC Class |
|--|---------|---------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | ≥ 8,000 | V    | 3B          |
| Electrostatic Discharge - Machine Model    | ESD MM  | ≥ 400   | V    | С           |

Note:

# Safe Operating Area and Derating Information (@TA = +25°C, unless otherwise specified.)



Safe Operating Areas (TO-92 Package)



Safe Operating Areas (TO-126 Package)

<sup>5.</sup> Pulse test for pulse width < 5ms, duty cycle ≤ 10%.

 $<sup>{\</sup>small 6.}\ \ Refer\ to\ JEDEC\ specification\ JESD22-A114\ and\ JESD22-A115.$ 



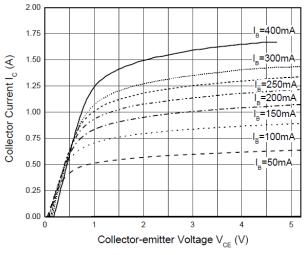
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                | Symbol               | Min           | Тур          | Max           | Unit | Test Condition   |
|---|----------------------|---------------|--------------|---------------|------|--|
| Collector-Emitter Voltage                     | BV <sub>CES</sub>    | 800           | _            | _             | V    | $I_C = 100 \mu A, V_{BE} = 0 V$  |
| Collector-Emitter Breakdown Voltage           | BV <sub>CEO</sub>    | 465           | _            | _             | V    | $I_C = 100\mu A$   |
| Emitter-Base Breakdown Voltage                | BV <sub>EBO</sub>    | 9             | _            | _             | V    | $I_E = 100\mu A$   |
| Collector Cutoff Current                      | I <sub>CEV</sub>     |               | _            | 10            | μA   | V <sub>CE</sub> = 800V, V <sub>BE</sub> = -1.5V  |
| DC current transfer Static ratio (Note 7)     | h <sub>FE</sub>      | 15<br>13<br>5 | 17<br>—      | —<br>30<br>25 |      | $I_C = 0.3A$ , $V_{CE} = 2V$<br>$I_C = 0.5A$ , $V_{CE} = 2V$<br>$I_C = 1.0A$ , $V_{CE} = 2V$ |
| Collector-Emitter Saturation Voltage (Note 7) | V <sub>CE(sat)</sub> | _             | 0.17<br>0.29 | 0.3<br>0.4    | V    | $I_C = 0.5A, I_B = 0.1A$<br>$I_C = 1A, I_B = 0.25A$  |
| Base-Emitter Saturation Voltage (Note 7)      | V <sub>BE(sat)</sub> | _             | _            | 1.0<br>1.2    | V    | $I_C = 0.5A, I_B = 0.1A$<br>$I_C = 1A, I_B = 0.25A$  |
| Output Capacitance                            | C <sub>ob</sub>      | _             | 16           | _             | pF   | V <sub>CB</sub> = 10V, f = 0.1MHz  |
| Transition Frequency                          | f <sub>T</sub>       | 4             | _            | _             | MHz  | I <sub>C</sub> = 0.1A, V <sub>CE</sub> = 10V   |
| Turn-on Time with Resistive Load              | ton                  |               | 0.3          | 1             |      |  |
| Storage Time with Resistive Load              | ts                   | _             | 1.8          | 3             | μs   | $I_C = 1A, V_{CC} = 125V, I_{B1} = 0.2A,$<br>$I_{B2} = -0.2A, t_D = 25\mu s$                 |
| Fall Time with Resistive Load                 | t <sub>f</sub>       | _             | 0.28         | 0.4           |      | 1820.2Λ, τρ - 20μs   |

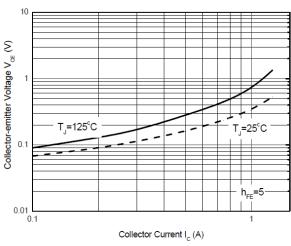
Note: 7. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



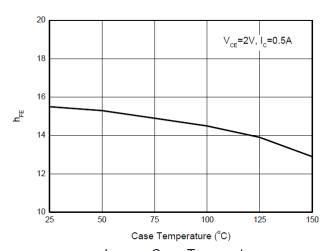
# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



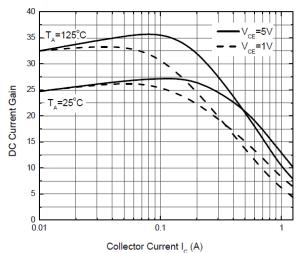
Static Characteristics



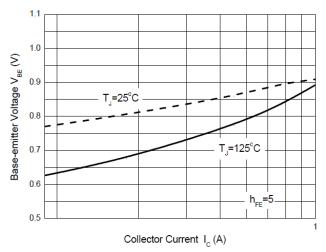
Collector-emitter Saturation Voltage



h<sub>FE</sub> vs. Case Temperature



DC Current Gain vs. Collector Current



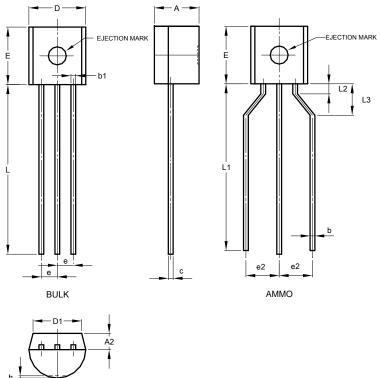
Base-emitter Saturation Voltage



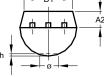
# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

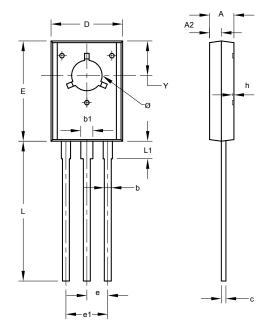
### TO92 Type C



| TO92 Type C          |         |       |      |  |  |
|----------------------|---------|-------|------|--|--|
| Dim                  | Min Max |       | Тур  |  |  |
| Α                    | 3.30    | 3.70  | -    |  |  |
| A2                   | 1.10    | 1.40  | -    |  |  |
| b                    | 0.38    | 0.55  | -    |  |  |
| С                    | 0.36    | 0.51  | -    |  |  |
| D                    | 4.40    | 4.70  | -    |  |  |
| D1                   | 3.430   | -     | -    |  |  |
| Е                    | 4.30    | 4.70  | -    |  |  |
| е                    | -       | -     | 1.27 |  |  |
| e2                   | 2.440   | 2.640 | -    |  |  |
| h                    | 0.00    | 0.38  | -    |  |  |
| L                    | 14.10   | 14.50 | -    |  |  |
| L1                   | 12.50   | 14.50 | -    |  |  |
| L3                   | 2.50    | 3.50  | -    |  |  |
| Ø                    | -       | 1.60  | -    |  |  |
| All Dimensions in mm |         |       |      |  |  |



#### TO126



| TO126                |         |       |       |  |  |
|----------------------|---------|-------|-------|--|--|
| Dim                  | Min Max |       | Тур   |  |  |
| Α                    | 2.400   | 2.900 | -     |  |  |
| A2                   | 1.060   | 1.500 | -     |  |  |
| b                    | 0.660   | 0.860 | -     |  |  |
| b1                   | 1.170   | 1.470 | -     |  |  |
| С                    | 0.400   | 0.600 | -     |  |  |
| D                    | 7.400   | 8.200 | -     |  |  |
| Е                    | 10.60   | 11.20 | -     |  |  |
| е                    | -       | -     | 2.280 |  |  |
| e1                   | -       | -     | 4.560 |  |  |
| h                    | 0.00    | 0.30  | -     |  |  |
| L                    | 14.50   | 15.90 | -     |  |  |
| L1                   | 1.700   | 2.100 | -     |  |  |
| Υ                    | 3.600   | 3.900 | -     |  |  |
| Ø                    | 3.100   | 3.550 | -     |  |  |
| All Dimensions in mm |         |       |       |  |  |

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals. Note:



#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

www.diodes.com